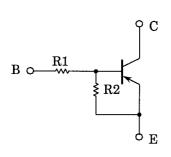
TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT Process)

## RN2201,RN2202,RN2203 RN2204,RN2205,RN2206

Switching, Inverter Circuit, Interface Circuit And Driver Circuit Applications

- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- ullet Complementary to RN1201~RN1206

### **Equivalent Circuit and Bias Resistor Values**



Type No.	R1 (kΩ)	R2 (kΩ)
RN2201	4.7	4.7
RN2202	10	10
RN2203	22	22
RN2204	47	47
RN2205	2.2	47
RN2206	4.7	47

# JEDEC — EIAJ O.55MAX. 4.2MAX. 80 NIWLZI 1.27,1.27 80 1. EMITTER 2. COLLECTPR 3. BASE JEDEC — EIAJ — TOSHIBA 2-4E1A

Weight: 0.13g

### **Maximum Ratings (Ta = 25°C)**

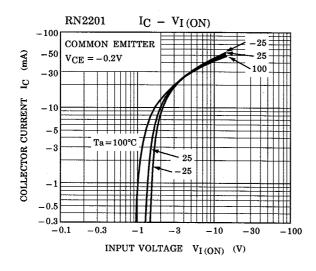
Characteristic		Symbol	Rating	Unit	
Collector-base voltage	RN2201~2206	V <sub>CBO</sub>	-50	V	
Collector-emitter voltage	1(142201 2200	V <sub>CEO</sub>	-50	V	
Emitter-base voltage	RN2201~2204	V <sub>EBO</sub>	-10	V	
	RN2205, 2206	VEBO.	-5		
Collector current		I <sub>C</sub>	-100	mA	
Collector power dissipation	RN2201~2206	PC	300	mW	
Junction temperature	KIN2201*2200	Tj	150	°C	
Storage temperature range		T <sub>stg</sub>	-55~150	°C	

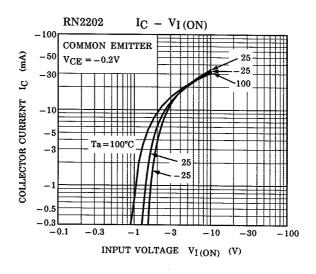


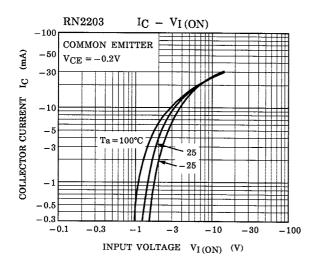
# Electrical Characteristics (Ta = 25°C)

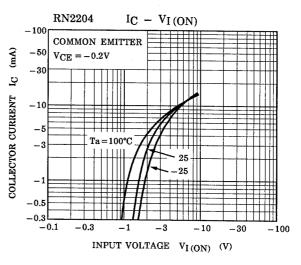
Characteris	stic	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	RN2201~2206	I <sub>CBO</sub>	_	$V_{CB} = -50V$ , $I_E = 0$	_	_	-100	nA
		I <sub>CEO</sub>	_	V <sub>CE</sub> = -50V, I <sub>B</sub> = 0		_	-500	IIA
Emitter cut-off current	RN2201	ІЕВО	_	V <sub>EB</sub> = −10V, I <sub>C</sub> = 0	-0.82	_	-1.52	- mA
	RN2202		_		-0.38	_	-0.71	
	RN2203		_		-0.17	_	-0.33	
	RN2204		_		-0.082	_	-0.15	
	RN2205		_	V <sub>EB</sub> = -5V, I <sub>C</sub> = 0	-0.078	_	-0.145	
	RN2206		_		-0.074	_	-0.138	
DC current gain	RN2201		_		30	_	_	_
	RN2202		_		50	_	_	
	RN2203	L	_	V <sub>CE</sub> = −5V,	70	_	_	
	RN2204	h <sub>FE</sub>	_	I <sub>C</sub> = -10mA	80	_	_	
	RN2205		_	-	80	_	_	
	RN2206		_		80	_	_	
Collector-emitter saturation voltage	RN2201~2206	V <sub>CE (sat)</sub>	_	I <sub>C</sub> = -5mA, I <sub>B</sub> = -0.25mA	_	-0.1	-0.3	٧
	RN2201	V <sub>I</sub> (ON)	_	V <sub>CE</sub> = -0.2V, I <sub>C</sub> = -5mA	-1.1	_	-2.0	. V
Input voltage (ON)	RN2202		_		-1.2	_	-2.4	
	RN2203		_		-1.3	_	-3.0	
	RN2204		_		-1.5	_	-5.0	
	RN2205		_		-0.6	_	-1.1	
	RN2206		_		-0.7	_	-1.3	
Input voltage (OFF)	RN2201~2204	V <sub>I (OFF)</sub>	_	V <sub>CE</sub> = -5V, I <sub>C</sub> = -0.1mA	-1.0	_	-1.5	V
	RN2205, 2206		_		-0.5	_	-0.8	
Translation frequency	RN2201~2206	f <sub>T</sub>	_	$V_{CE} = -10V, I_{C} = -5mA$	_	200	_	MHz
Collector output capacitance	RN2201~2206	C <sub>ob</sub>	_	$V_{CB} = -10V, I_E = 0,$ f = 1MHz	_	3	6	pF
Input resistor	RN2201	R1	_		3.29	4.7	6.11	kΩ
	RN2202		_		7	10	13	
	RN2203		_		15.4	22	28.6	
	RN2204		_		32.9	47	61.1	
	RN2205		_		1.54	2.2	2.86	
	RN2206		_		3.29	4.7	6.11	
Resistor ratio	RN2201~2204	R1/R2	_	_	0.9	1.0	1.1	_
	RN2205		_		0.0421	0.0468	0.0515	
	RN2206		_		0.09	0.1	0.11	

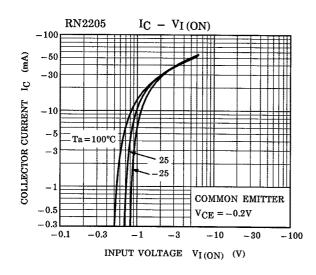
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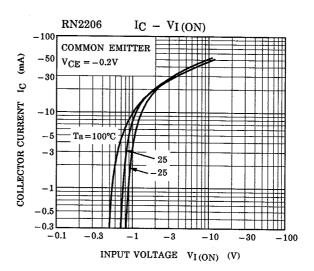




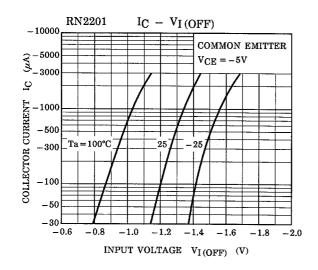


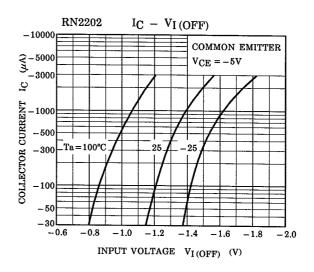


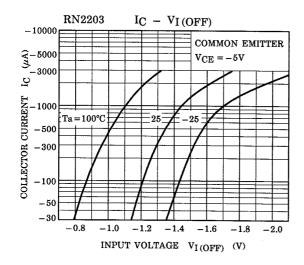


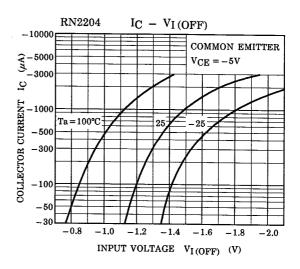


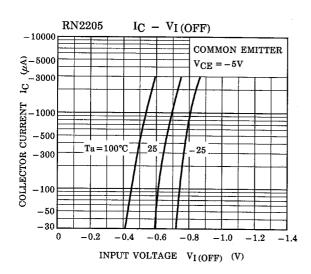
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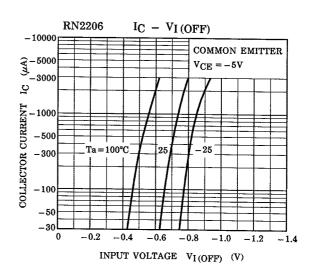


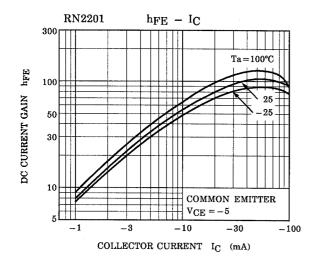


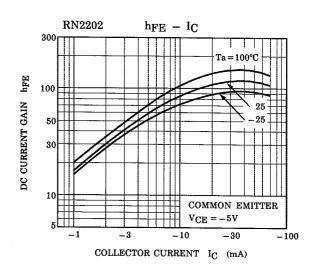


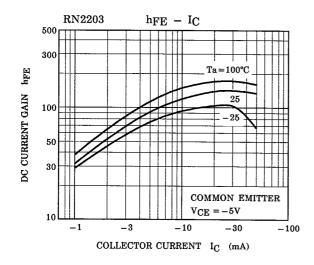


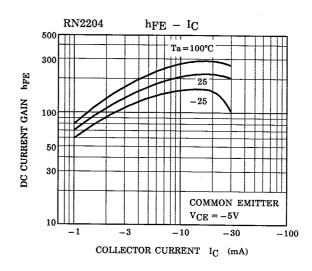


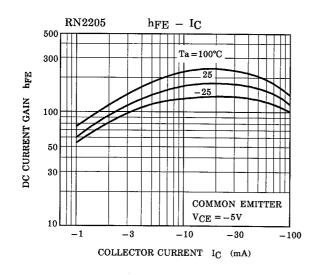


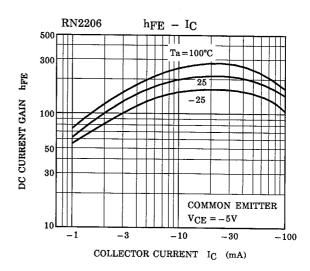












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